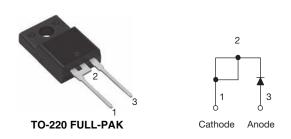


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Fast Soft Recovery Rectifier Diode, 20 A



PRODUCT SUMMARY					
Package	TO-220FP				
I _{F(AV)}	20 A				
V _R	200 V, 400 V, 600 V				
V _F at I _F	1.3 V				
I _{FSM}	300 A				
t _{rr}	60 ns				
T _J max.	150 °C				
Diode variation	Single die				
Snap factor	0.6				

FEATURES

- · Glass passivated pellet chip junction
- 150 °C max. operation junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 approved
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-20ETF0..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Sinusoidal waveform	20	А		
V _{RRM}		200 to 600	V		
I _{FSM}		300	А		
V _F	10 A, T _J = 25 °C	1.2	V		
t _{rr}	1 A, 100 A/μs	60	ns		
TJ		-40 to +150	°C		

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA		
VS-20ETF02FPPbF, VS-20ETF02FP-M3	200	300			
VS-20ETF04FPPbF, VS-20ETF04FP-M3	400	500	5		
VS-20ETF06FPPbF, VS-20ETF06FP-M3	600	700			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL TEST CONDITIONS VALUES U		UNITS		
Maximum average forward current	I _{F(AV)}	T _C = 51 °C, 180° conduction half sine wave	20		
Maximum peak one cycle non-repetitive	I	10 ms sine pulse, rated V _{RRM} applied	250	Α	
surge current	IFSM	10 ms sine pulse, no voltage reapplied	300		
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s	
Maximum I-t for fusing	I-t	10 ms sine pulse, no voltage reapplied	442	A-5	
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A ² √s	



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward valtage drep	V	20 A, T _J = 25 °C		1.30	V
Maximum forward voltage drop	V_{FM}	60 A, T _J = 25 °C		1.67	V
Forward slope resistance	r _t	T _J = 150 °C		12.5	mΩ
Threshold voltage	V _{F(TO)}	T _J = 150 °C		0.9	V
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	V _R = Rated V _{RRM}	0.1	mA mA
		T _J = 150 °C		5.0	

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	<u> </u>
Reverse recovery time	t _{rr}	I _F at 20 A _{pk}	160	ns	I _{FM} †
Reverse recovery current	I _{rr}	100 A/μs	10	Α	$t_a \mid t_b$
Reverse recovery charge	Q _{rr}	25 °C	1.25	μC	dir/ dt Q _{rr}
Snap factor	S	Typical	0.6		I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and temperature range	l storage	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resignation to case	stance,	R_{thJC}	DC operation	2.5	
Maximum thermal resignation to ambient	stance,	R _{thJA}		62	°C/W
Typical thermal resista case to heatsink	nce,	R _{thCS}	Mounting surface, smooth, and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	OZ.
Mounting torque	minimum			6 (5)	kgf · cm
Mounting torque	maximum			12 (10)	(lbf · in)
				20ETF	02FP
Marking device		Case style TO-220 FULL-PAK	20ETF04FP		
				20ETF	06FP

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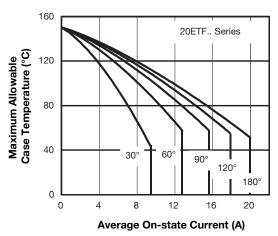


Fig. 1 - Current Rating Characteristics

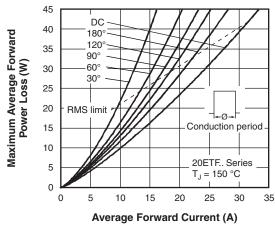


Fig. 4 - Forward Power Loss Characteristics

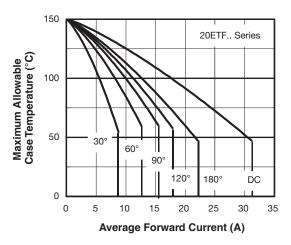


Fig. 2 - Current Rating Characteristics

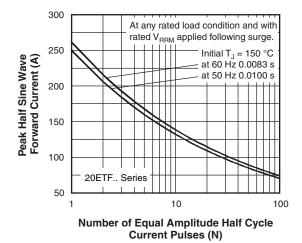


Fig. 5 - Maximum Non-Repetitive Surge Current

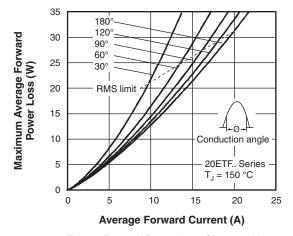


Fig. 3 - Forward Power Loss Characteristics

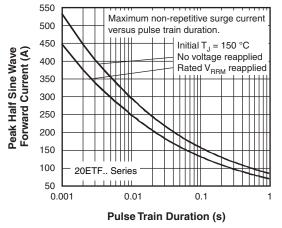


Fig. 6 - Maximum Non-Repetitive Surge Current



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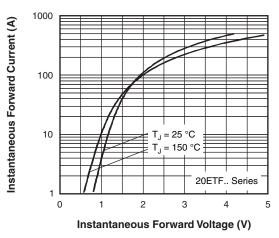


Fig. 7 - Forward Voltage Drop Characteristics

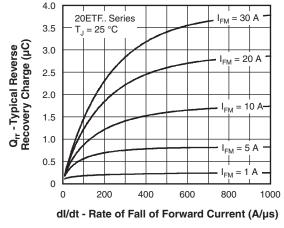


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

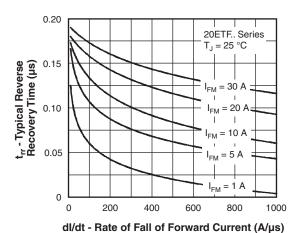


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

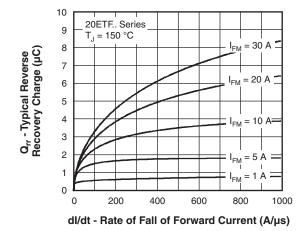


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

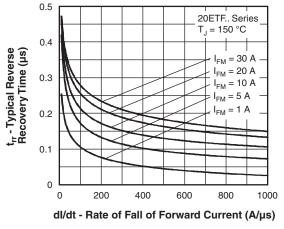


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

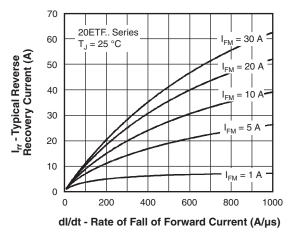


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

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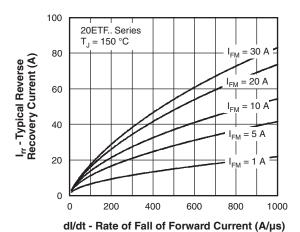


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

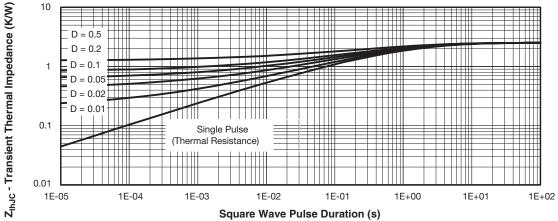
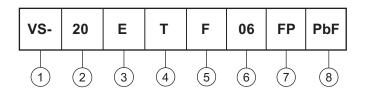


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Current rating (20 = 20 A)

Circuit configuration:

E = single diode

Package:

T = TO-220

5 Type of silicon:

F = fast soft recovery rectifier

02 = 200 V Voltage code x 100 = V_{RRM} 04 = 400 V

FULL-PAK

Environmental digit:

• PbF = lead (Pb)-free and RoHS-compliant

• -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

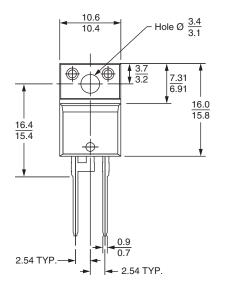
06 = 600 V

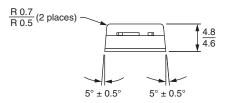
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-20ETF02FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETF02FP-M3	50	1000	Antistatic plastic tubes		
VS-20ETF04FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETF04FP-M3	50	1000	Antistatic plastic tubes		
VS-20ETF06FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETF06FP-M3	50	1000	Antistatic plastic tubes		

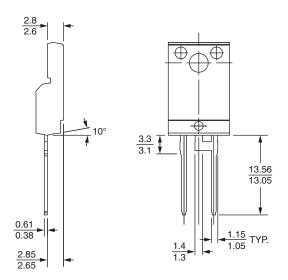
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95005</u>				
Deut as addis a information	TO-220 FP PbF	www.vishay.com/doc?95009		
Part marking information	TO-220 FP -M3	www.vishay.com/doc?95440		
SPICE model		www.vishay.com/doc?95410		

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DIMENSIONS in millimeters







Lead assignments

Diodes

1 + 2 - Cathode

3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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